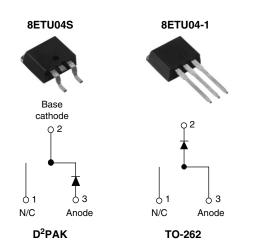


Vishay High Power Products

Ultrafast Rectifier, 8 A FRED Pt[™]



PRODUCT SUMMARY				
t _{rr}	60 ns			
I _{F(AV)}	8 A			
V _R	400 V			

FEATURES

- · Ultrafast recovery time
- Low forward voltage drop
- · Low leakage current
- 175 °C operating junction temperature
- Designed and qualified for industrial level

DESCRIPTION/APPLICATIONS

FRED Pt[™] series are the state of the art ultrafast recovery rectifiers specifically designed with optimized performance of forward voltage drop and ultrafast recovery time.

The planar structure and the platinum doped life time control, guarantee the best overall performance, ruggedness and reliability characteristics.

These devices are intended for use in the output rectification stage of SMPS, UPS, dc-to-dc converters as well as freewheeling diode in low voltage inverters and chopper motor drives.

Their extremely optimized stored charge and low recovery current minimize the switching losses and reduce over dissipation in the switching element and snubbers.

ABSOLUTE MAXIMUM RATINGS					
PARAMETER	SYMBOL	TEST CONDITIONS	MAX.	UNITS	
Repetitive peak reverse voltage	V _{RRM}		400	V	
Average rectified forward current	I _{F(AV)}	T _C = 155 °C	8		
Non-repetitive peak surge current	I _{FSM}	T _C = 25 °C	100	А	
Repetitive peak forward current	I _{FRM}		16		
Operating junction and storage temperatures	T _J , T _{Stg}		- 65 to 175	°C	

ELECTRICAL SPECIFICATIONS (T _J = 25 °C unless otherwise specified)							
PARAMETER	SYMBOL	TEST CONDITIONS MIN. TY			MAX.	UNITS	
Breakdown voltage, blocking voltage	V _{BR} , V _R	I _R = 100 μA	400	-	-		
Forward voltage	VF	I _F = 8 A	-	1.19	1.3	V	
Forward voltage	۷F	I _F = 8 A, T _J = 150 °C	-	0.94	1.0		
		$V_{R} = V_{R}$ rated	-	0.2	10	A	
Reverse leakage current I _R		$T_J = 150 \ ^{\circ}C, \ V_R = V_R \ rated$	-	20	500	μΑ	
Junction capacitance	CT	V _R = 400 V	-	14	-	pF	
Series inductance	L _S	Measured lead to lead 5 mm from package body -		8.0	-	nH	

8ETU04S/8ETU04-1

Vishay High Power Products

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DYNAMIC RECOVERY CHARACTERISTICS ($T_J = 25 \text{ °C}$ unless otherwise specified)							
PARAMETER	SYMBOL	TEST CONDITIONS		MIN.	TYP.	MAX.	UNITS
			$= 50 \text{ A/}\mu\text{s}, \text{ V}_{\text{R}} = 30 \text{ V}$	-	35	60	
Reverse recovery time	t _{rr}	T _J = 25 °C		-	43	-	ns
		T _J = 125 °C	I _F = 8 A dI _F /dt = 200 A/μs V _R = 200 V	-	67	-	
Peak recovery current I _{RRM}	I _{RRM}	T _J = 25 °C		-	2.8	-	A
		T _J = 125 °C		-	6.3	-	
Reverse recovery charge Q _{rr}	0	T _J = 25 °C		-	60	-	nC
	Qrr	T _J = 125 °C		-	210	-	

THERMAL - MECHANICAL SPECIFICATIONS							
PARAMETER	SYMBOL	TEST CONDITIONS	MIN.	TYP.	MAX.	UNITS	
Maximum junction and storage temperature range	T _J , T _{Stg}		- 65	-	175	°C	
Thermal resistance, junction to case	R _{thJC}		-	1.8	2.0		
Thermal resistance, junction to ambient	R _{thJA}	Typical socket mount	-	-	50	°C/W	
Thermal resistance, case to heatsink	R _{thCS}	Mounting surface, flat, smooth and greased	-	0.5	-		
Weight			-	2.0	-	g	
weight			-	0.07	-	oz.	
Mounting torque			6.0 (5.0)	-	12 (10)	kgf ⋅ cm (lbf ⋅ in)	
Marking davias		Case style D ² PAK		8ETU04S		•	
Marking device		Case style TO-262		8ETU04-1			

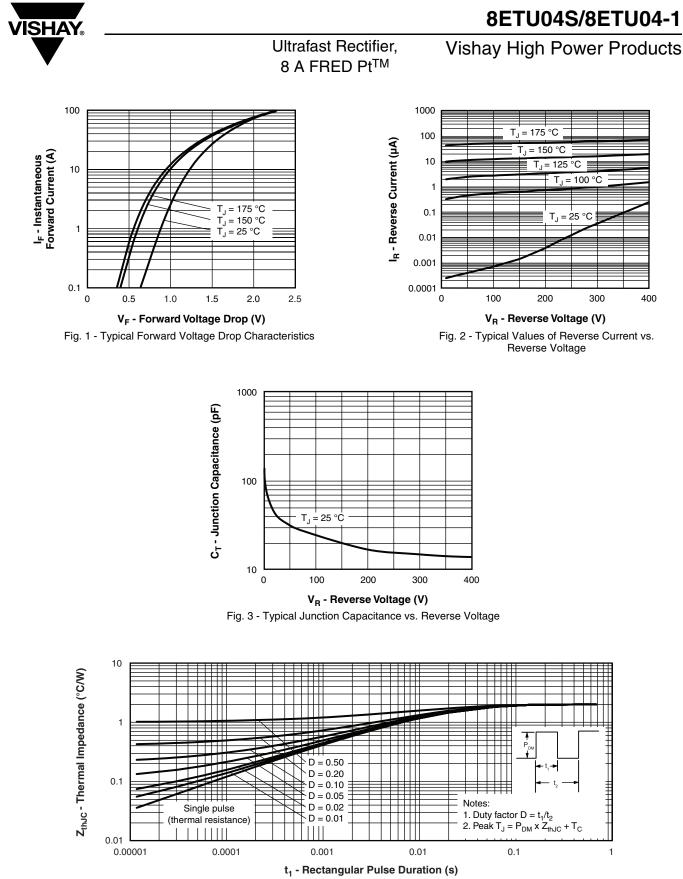


Fig. 4 - Maximum Thermal Impedance ZthJC Characteristics

8ETU04S/8ETU04-1

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Ultrafast Rectifier, 8 A FRED Pt[™]

90

80

70

60

50

40

30

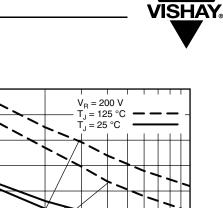
20

100

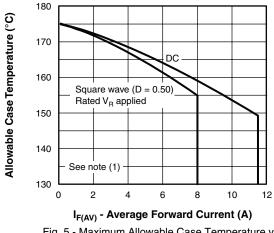
I_F = 16

= 8 A

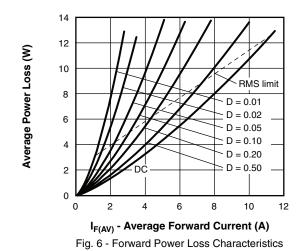
t_{rr} (ns)



1000

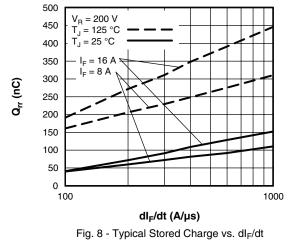






Note

- $^{(1)} \mbox{ Formula used: } T_C = T_J (Pd + Pd_{REV}) \ x \ R_{thJC}; \\ Pd = \mbox{ Forward power loss } = I_{F(AV)} \ x \ V_{FM} \ at \ (I_{F(AV)}/D) \ (see \ fig. \ 6); \\ Pd_{REV} = \mbox{ Inverse power loss } = V_{R1} \ x \ I_R \ (1 D); \ I_R \ at \ V_{R1} = \ Rated \ V_R$



dl_F/dt (A/µs)

Fig. 7 - Typical Reverse Recovery Time vs. dl_F/dt



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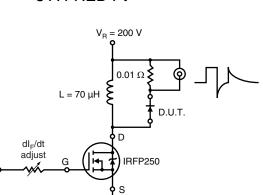
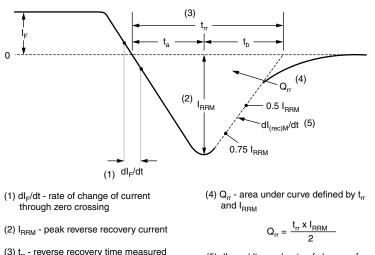


Fig. 9 - Reverse Recovery Parameter Test Circuit



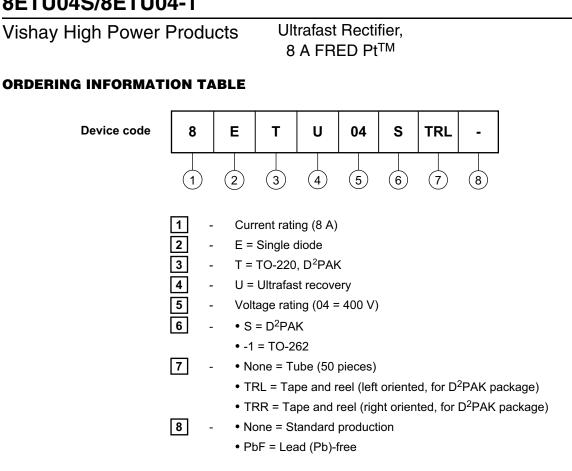
(3) t_{rr} - reverse recovery time measured from zero crossing point of negative going ${\rm I}_{\rm F}$ to point where a line passing through 0.75 I_{RRM} and 0.50 I_{RRM} extrapolated to zero current.

П

(5) dI_{(rec)M}/dt - peak rate of change of current during t_b portion of t_{rr}

Fig. 10 - Reverse Recovery Waveform and Definitions

8ETU04S/8ETU04-1



LINKS TO RELATED DOCUMENTS					
Dimensions http://www.vishay.com/doc?95014					
Part marking information http://www.vishay.com/doc?95008					
Packaging information http://www.vishay.com/doc?95032					



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